

Q.bloxx XL A106

Measurement Module for Strain Gage and LVDT/RVDT

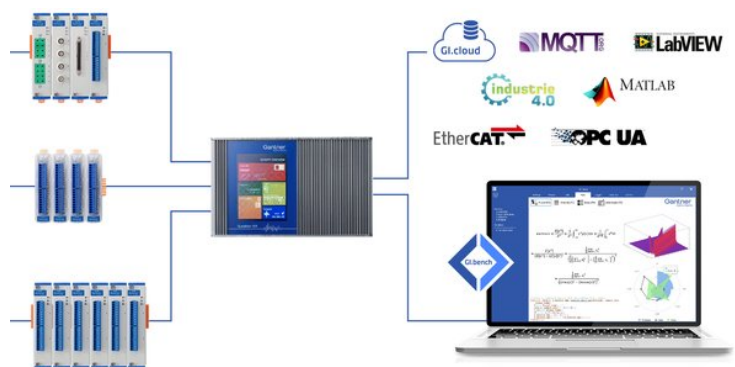
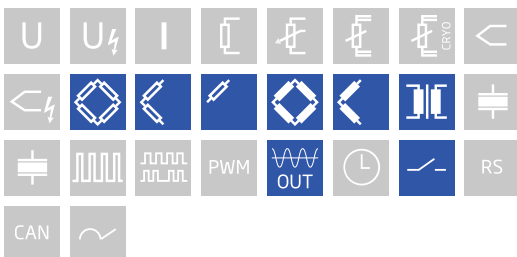
Q.bloxx XL is a new addition to the Q.series product family - the ideal DAQ solution for widely distributed installations that require higher performance and custom sensor terminations. Q.bloxx XL products are packaged in modular, DIN Rail mountable enclosures that easily snap together for system expansion. Flexibility in distribution allows for highly synchronized data that is less prone to noise due to shorter sensor cable runs to the subject.

- RS485 fieldbus interface up to 48 Mbps: LocalBus, up to 115.2 kbps: Modbus-RTU, ASCII
- Electromagnetic Compatibility according to EN61000-4 and EN55011
- Connectable to Controller Q.station X
- Power supply 10 ... 30 VDC
- DIN rail mounting (EN60715)



Key Features

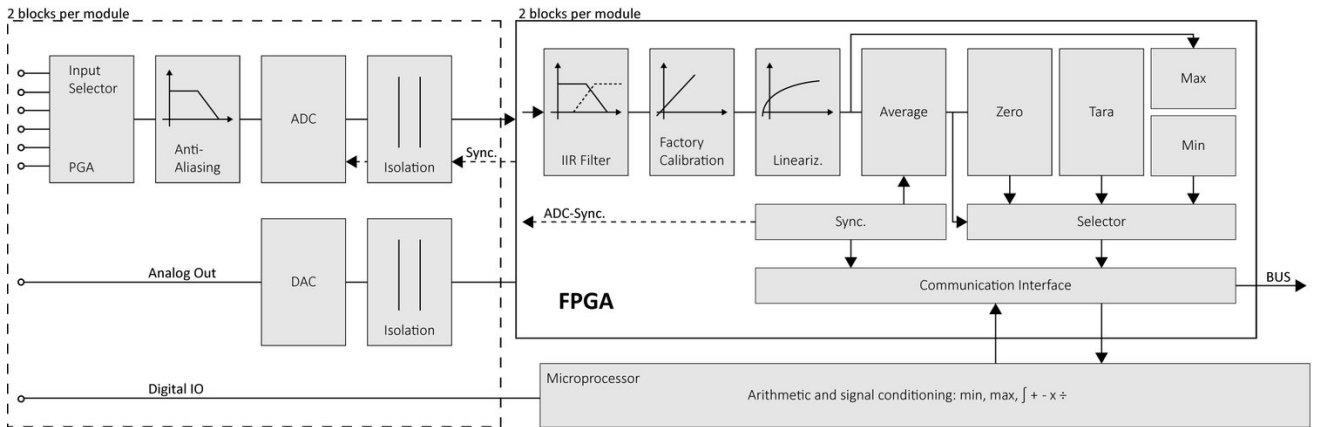
- 2 galvanically isolated analog inputs channels
Strain gage and inductive half and full bridges, LVDT, RVDT quarter bridge with completion terminal
- DC and carrier frequency (CF) principle
2.5 and 5 VDC excitation, 2.5 and 5 VDCeff excitation carrier frequency, 600 Hz or 4.8 kHz configurable per channel
- 2 Analog output channels
± 10 VDC, 20 kHz update rate per channel
- High-accuracy digitization
24-bit ADC, 20 kHz sample rate per channel
- 4 digital I/Os
Input: state, tare, memory reset, output: state, alarm, threshold
- Signal conditioning
Linearization, filtering, average, scaling, min/max, RMS, arithmetic, alarm
- 3-Way galvanic isolation
Channel to channel, channel to power supply, and channel to bus



Q.bloxx XL A106

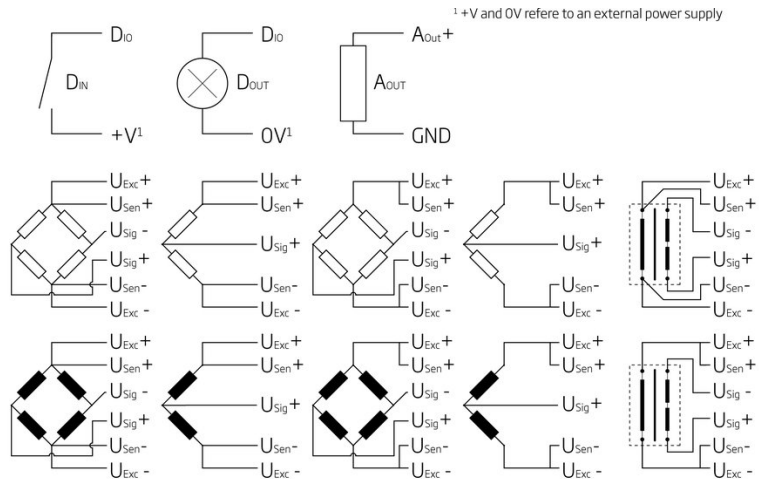
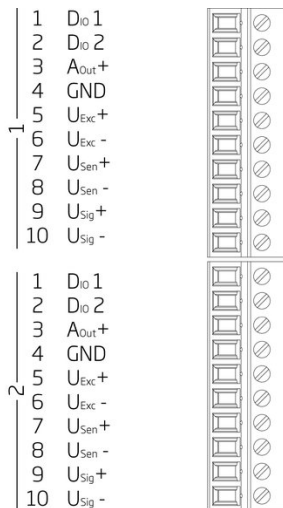
Measurement Module for Strain Gage and LVDT/RVDT

Block diagram



Technical Data

Terminal assignment 10pole screw



Analog Input

Channels	2
Input impedance	> 10 MΩ
Isolation voltage	500 VDC channel to channel, to power supply, channel to bus ¹

¹ noise pulses up to 1000 VDC, continuous up to 250 VDC

Strain Gage Measurement

Bridge configuration(s)	Resistive full-bridge (4/6-wire) resistive half-bridge (3/5-wire) resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)			
Allowable sensor cable length	< 30 m			
Shunt resistor	100 kΩ internal resistor			
Bridge excitation	2.5 - 5 VDC 2.5 - 5 V _{eff} (Carrier Frequency)			
Bridge excitation stability	< 0.01 % / 24 hrs			
Bridge excitation drift	< 0.02 % / 10 K			
	5 VDC	5 V_{eff} (CF)	2.5 VDC	2.5 V_{eff} (CF)
Allowable sensor resistance	> 300 Ω	> 300 Ω	> 100 Ω	> 100 Ω
Input range	± 1.25 mV / V	± 1.25 mV / V	± 2.5 mV / V	± 2.5 mV / V
	± 2.5 mV / V	± 2.5 mV / V	± 5 mV / V	± 5 mV / V
	± 25 mV / V	± 25 mV / V	± 50 mV / V	± 50 mV / V
	± 50 mV / V	± 50 mV / V	± 100 mV / V	± 100 mV / V
	± 100 mV / V	± 100 mV / V	± 200 mV / V	± 200 mV / V
	± 200 mV / V	± 200 mV / V	± 400 mV / V	± 400 mV / V
	± 500 mV / V	± 500 mV / V	± 1000 mV / V	± 1000 mV / V
Long-term stability	< 0.2 μV / V / 24 hrs (DC excitation) < 0.1 μV / V / 24 hrs (CF excitation)		< 2 μV / V / 8000 hrs (DC excitation) < 1 μV / V / 8000 hrs (CF excitation)	
Temperature drift (range 2.5 mV/V)	< 0.2 μV / V / 10 K offset drift		< 0.05 % / 10 K gain drift	
Noise (range 2.5 mV/V)	0.3 μV / V at 0 up to 10 Hz		1 μV / V at 10 up to 1 kHz	

Strain Gage Measurement (Supply: 5 VDC)

Bridge configuration(s)	Resistive full-bridge (4/6-wire), resistive half-bridge (3/5-wire) resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)							
Allowable sensor cable length	< 30 m							
Shunt resistor	100 kΩ internal resistor							
Bridge power supply stability	< 0.01 % / 24 h							
Bridge power supply drift	< 0.02 % / 10 K							
Allowable sensor resistance	> 300 Ω							
Measurement range	± 500 mV / V	± 200 mV / V	± 100 mV / V	± 50 mV / V	± 25 mV / V	± 2.5 mV / V	± 1.25 mV / V	
Margin of error	200 μV / V	80 μV / V	40 μV / V	20 μV / V	10 μV / V	1 μV / V	0.5 μV / V	
Long-term stability 24 h	20 μV / V	8 μV / V	4 μV / V	2 μV / V	1 μV / V	0.1 μV / V	0.05 μV / V	
	8000 h	80 μV / V	40 μV / V	20 μV / V	10 μV / V	1 μV / V	0.5 μV / V	
Temperature drift offset drift	20 μV / V / 10 K	8 μV / V / 10 K	4 μV / V / 10 K	2 μV / V / 10 K	1 μV / V / 10 K	0.1 μV / V / 10 K	0.05 μV / V / 10 K	
Measuring range end value	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	
Noise no filter	60 μV / V _{pp}	24 μV / V _{pp}	11 μV / V _{pp}	8 μV / V _{pp}	3.8 μV / V _{pp}	4.5 μV / V _{pp}	2.8 μV / V _{pp}	
Noise 1kHz filter	18 μV / V _{pp}	9 μV / V _{pp}	4 μV / V _{pp}	3.5 μV / V _{pp}	1.6 μV / V _{pp}	2.2 μV / V _{pp}	1.4 μV / V _{pp}	
Noise 10 Hz filter	1 μV / V _{pp}	0.6 μV / V _{pp}	0.3 μV / V _{pp}	0.22 μV / V _{pp}	0.2 μV / V _{pp}	0.2 μV / V _{pp}	0.1 μV / V _{pp}	

Strain Gage Measurement (Supply: 5 Veff 600 Hz TF-excitation)

Bridge configuration(s)	Resistive full-bridge (4/6-wire), resistive half-bridge (3/5-wire) inductive full-bridge (4/6-wire), inductive half-bridge (3/5-wire), LVDT resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)						
Bridge power supply stability	< 0.01 % / 24 h						
Bridge power supply drift	< 0.02 % / 10 K						
Allowable sensor resistance	> 300 Ω						
Measurement range	± 500 mV / V	± 200 mV / V	± 100 mV / V	± 50 mV / V	± 25 mV / V	± 2.5 mV / V	± 1.25 mV / V
Margin of error	200 μV / V	80 μV / V	40 μV / V	20 μV / V	10 μV / V	1 μV / V	0.5 μV / V
Long-term stability 24 h	20 μV / V	8 μV / V	4 μV / V	2 μV / V	1 μV / V	0.1 μV / V	0.05 μV / V
8000 h	200 μV / V	80 μV / V	40 μV / V	20 μV / V	10 μV / V	1 μV / V	0.5 μV / V
Temperature drift offset drift	20 μV / V / 10 K	8 μV / V / 10 K	4 μV / V / 10 K	2 μV / V / 10 K	1 μV / V / 10 K	0.1 μV / V / 10 K	0.05 μV / V / 10 K
Measuring range end value	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K
Noise 100 Hz filter	27 μV / Vpp	12 μV / Vpp	6 μV / Vpp	3.5 μV / Vpp	1.5 μV / Vpp	0.6 μV / Vpp	1.35 μV / Vpp
Noise 10 Hz filter	2.5 μV / Vpp	1.2 μV / Vpp	0.6 μV / Vpp	0.4 μV / Vpp	0.2 μV / Vpp	0.16 μV / Vpp	0.1 μV / Vpp

Strain Gage Measurement (Supply: 5 Veff 4.8 kHz TF-excitation)

Bridge configuration(s)	Resistive full-bridge (4/6-wire), resistive half-bridge (3/5-wire) inductive full-bridge (4/6-wire), inductive half-bridge (3/5-wire), LVDT resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)						
Bridge power supply stability	< 0.01 % / 24 h						
Bridge power supply drift	< 0.02 % / 10 K						
Allowable sensor resistance	> 300 Ω						
Measurement range	± 500 mV / V	± 200 mV / V	± 100 mV / V	± 50 mV / V	± 25 mV / V	± 2.5 mV / V	± 1.25 mV / V
Margin of error	200 μV / V	80 μV / V	40 μV / V	20 μV / V	10 μV / V	2.5 μV / V	1.25 μV / V
Long-term stability 24 h	20 μV / V	8 μV / V	4 μV / V	2 μV / V	1 μV / V	0.25 μV / V	0.15 μV / V
8000 h	200 μV / V	80 μV / V	40 μV / V	20 μV / V	10 μV / V	2.5 μV / V	1.25 μV / V
Temperature drift offset drift	20 μV / V / 10 K	8 μV / V / 10 K	4 μV / V / 10 K	2 μV / V / 10 K	1 μV / V / 10 K	0.2 μV / V / 10 K	0.1 μV / V / 10 K
Measuring range end value	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K
Noise no filter	70 μV / Vpp	35 μV / Vpp	15 μV / Vpp	8 μV / Vpp	3.8 μV / Vpp	2.5 μV / Vpp	1.4 μV / Vpp
Noise 1kHz filter	9 μV / Vpp	4 μV / Vpp	2 μV / Vpp	1.5 μV / Vpp	0.7 μV / Vpp	0.7 μV / Vpp	0.5 μV / Vpp
Noise 10 Hz filter	1.5 μV / Vpp	0.7 μV / Vpp	0.4 μV / Vpp	0.25 μV / Vpp	0.12 μV / Vpp	0.2 μV / Vpp	0.12 μV / Vpp

Strain Gage Measurement (Supply: 2.5 VDC)

Bridge configuration(s)	resistive full-bridge (4/6-wire), resistive half-bridge (3/5-wire) resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)						
Allowable sensor cable length	< 30 m						
Shunt resistor	100 kΩ internal resistor						
Bridge power supply stability	< 0.01 % / 24 h						
Bridge power supply drift	< 0.02 % / 10 K						
Allowable sensor resistance	> 100 Ω						
Measurement range	± 1000 mV / V	± 400 mV / V	± 200 mV / V	± 100 mV / V	± 50 mV / V	± 5 mV / V	± 2.5 mV / V
Margin of error	400 μV / V	160 μV / V	80 μV / V	40 μV / V	20 μV / V	2 μV / V	0.1 μV / V
Long-term stability 24 h	40 μV / V	16 μV / V	8 μV / V	4 μV / V	2 μV / V	0.2 μV / V	0.01 μV / V
8000 h	400 μV / V	160 μV / V	80 μV / V	40 μV / V	20 μV / V	2 μV / V	0.1 μV / V
Temperature drift offset drift	40 μV / V / 10 K	16 μV / V / 10 K	8 μV / V / 10 K	4 μV / V / 10 K	2 μV / V / 10 K	0.2 μV / V / 10 K	0.01 μV / V / 10 K
Measuring range end value	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K
Noise no filter	100 μV / Vpp	50 μV / Vpp	25 μV / Vpp	15 μV / Vpp	8 μV / Vpp	8 μV / Vpp	5 μV / Vpp
Noise 1kHz filter	40 μV / Vpp	16 μV / Vpp	8 μV / Vpp	6 μV / Vpp	3 μV / Vpp	4.5 μV / Vpp	2.2 μV / Vpp
Noise 10 Hz filter	2.5 μV / Vpp	1 μV / Vpp	0.5 μV / Vpp	0.4 μV / Vpp	0.2 μV / Vpp	0.3 μV / Vpp	0.2 μV / Vpp

Strain Gage Measurement (Supply: 2.5 Veff 600 Hz TF-Excitation)

Bridge configuration(s)	Resistive full-bridge (4/6-wire), resistive half-bridge (3/5-wire) inductive full-bridge (4/6-wire), inductive half-bridge (3/5-wire), LVDT resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)						
Bridge power supply stability	< 0.01 % / 24 h						
Bridge power supply drift	< 0.02 % / 10 K						
Allowable sensor resistance	> 100 Ω						
Measurement range	± 1000 mV / V	± 400 mV / V	± 200 mV / V	± 100 mV / V	± 50 mV / V	± 5 mV / V	± 2.5 mV / V
Margin of error	400 μV / V	160 μV / V	80 μV / V	40 μV / V	20 μV / V	2 μV / V	0.1 μV / V
Long-term stability 24 h	40 μV / V	16 μV / V	8 μV / V	4 μV / V	2 μV / V	0.2 μV / V	0.01 μV / V
8000 h	400 μV / V	160 μV / V	80 μV / V	40 μV / V	20 μV / V	2 μV / V	0.1 μV / V
Temperature drift offset drift	40 μV / V / 10 K	16 μV / V / 10 K	8 μV / V / 10 K	4 μV / V / 10 K	2 μV / V / 10 K	0.2 μV / V / 10 K	0.01 μV / V / 10 K
Measuring range end value	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K
Noise 100 Hz filter	60 μV / Vpp	30 μV / Vpp	10 μV / Vpp	6 μV / Vpp	3 μV / Vpp	1 μV / Vpp	0.5 μV / Vpp
Noise 10 Hz filter	5 μV / Vpp	2.5 μV / Vpp	1.2 μV / Vpp	0.8 μV / Vpp	0.5 μV / Vpp	0.4 μV / Vpp	0.2 μV / Vpp

Strain Gage Measurement (Supply: 2.5 V_{eff} 4.8 kHz TF-excitation)

Bridge configuration(s)	Resistive full-bridge (4/6-wire), resistive half-bridge (3/5-wire) inductive full-bridge (4/6-wire), inductive half-bridge (3/5-wire), LVDT resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)						
Bridge power supply stability	< 0.01 % / 24 h						
Bridge power supply drift	< 0.02 % / 10 K						
Allowable sensor resistance	> 100 Ω						
Measurement range	± 1000 mV/V	± 400 mV/V	± 200 mV/V	± 100 mV/V	± 50 mV/V	± 5 mV/V	± 2.5 mV/V
Margin of error	400 μV/V	160 μV/V	80 μV/V	40 μV/V	20 μV/V	5 μV/V	0.25 μV/V
Long-term stability 24 h	40 μV/V	16 μV/V	8 μV/V	4 μV/V	2 μV/V	0.5 μV/V	0.03 μV/V
8000 h	400 μV/V	160 μV/V	80 μV/V	40 μV/V	20 μV/V	5 μV/V	0.3 μV/V
Temperature drift offset drift	40 μV/V / 10 K	16 V/V / 10 K	8 μV/V / 10 K	4 μV/V / 10 K	2 μV/V / 10 K	0.5 μV/V / 10 K	0.03 μV/V / 10 K
Measuring range end value	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K	0.05 % / 10 K
Noise 1 kHz filter	140 μV / V _{pp}	70 μV / V _{pp}	35 μV / V _{pp}	16 μV / V _{pp}	8 μV / V _{pp}	5 μV / V _{pp}	3 μV / V _{pp}
Noise 100 Hz filter	16 μV / V _{pp}	8 μV / V _{pp}	4 μV / V _{pp}	2 μV / V _{pp}	1 μV / V _{pp}	1 μV / V _{pp}	0.8 μV / V _{pp}
Noise 10 Hz filter	3 μV / V _{pp}	1.5 μV / V _{pp}	0.8 μV / V _{pp}	0.5 μV / V _{pp}	0.3 μV / V _{pp}	0.3 μV / V _{pp}	0.2 μV / V _{pp}

LVDT/RVDT Measurement

Sensor connection	4- / 6-wire	
Sensor excitation (selectable)	5 V_{eff}	2.5 V_{eff}
Allowable sensor resistance	> 300 Ω	> 100 Ω
Input range	± 1.25 mV / V	± 2.5 mV / V
	± 2.5 mV / V	± 5 mV / V
	± 25 mV / V	± 50 mV / V
	± 50 mV / V	± 100 mV / V
	± 100 mV / V	± 200 mV / V
	± 200 mV / V	± 400 mV / V
	± 500 mV / V	± 1000 mV / V
Allowable sensor cable length	< 100 m ¹	
Long-term stability	< 0.1 μV / V / 24 hrs	< 1 μV / V / 8000 hrs
Temperature drift (range 2.5 mV/V)	< 0.2 μV / V / 10 K offset drift	< 0.05 % / 10 K gain drift
Signal-to-noise ratio	< 0.3 μV / V at 10 Hz	< 1 μV / V at 100 Hz

¹ low capacity sensor cable is strongly recommended

Analog Output

Channels	2	
Accuracy	0.02 % typical	
Voltage output	± 10 VDC	
Allowable load resistance	> 2 kΩ	
Long-term drift	< 1 mV / 24 hrs	< 2.5 mV / 8000 hrs
Temperature drift	< 1 mV / 10 K offset drift	< 0.05 % / 10 K gain drift
Noise voltage	< 2 mV at 10 Hz	< 10 mV at 1 kHz
	includes a 3rd order Sallen-Key low-pass filter with a cutoff frequency of 10.4 kHz	

Digital Input & Output

Channels	4 Configurable I/Os
Input	status
Input voltage	30 VDC max.
Logic voltage	< 2 VDC (Low) > 10 VDC (High)
Input type	PNP (current sinking)
Output voltage	10 to 30 VDC (external supply required)
Contact	open drain p-channel MOSFET
Load capacity	30 VDC / 100 mA (ohmic load)

Analog-to-Digital Conversion

Resolution	24-bit
Sample rate	20 kHz per channel
Modulation method	Sigma-delta
Anti-aliasing filter	2 kHz, 3th order (DC excitation) 1 kHz, 3th order (4.8 kHz CF excitation) 100 Hz, 3th order (600 Hz CF excitation)
Digital filters	Infinite impulse response (IIR), low-pass, high-pass, band-pass, band-stop, Butterworth or Bessel (2nd, 4th, 6th or 8th order), frequency range 0.1 Hz to 1 kHz in steps of 0.1 (adjustable via software)
Averaging	Configurable or automatic according to the user-defined data rate

Digital-to-Analog Conversion

Resolution	16-bit
Update rate	20 kHz per channel
Settling time	3 μ s

Communication Interface Localbus

Protocols	Proprietary LocalBus (115200 bps to 48 Mbps, latency <100 ns) ASCII (19200 bps to 115200 bps) Modbus RTU
Data format	8E1
Electrical standard	ANSI/TIA/EIA-485-A, 2-wire

Power Supply

Input voltage	10 to 30 VDC, overvoltage and overcurrent protection
Power consumption	approx. 2 W
Input voltage influence	< 0.001 %/V
Sensor excitation VS	20 V up to 30 V

Q.bloxx XL A106

Measurement Module for Strain Gage and LVDT/RVDT

Environmental Specifications

Electromagnetic compatibility (EMC)	according to IEC 61000-4 and EN 55011
Operating temperature	-20 °C to +60 °C
Storage temperature	-40 °C to +85 °C
Relative humidity	5 % to 95 % at 50 °C, non-condensing

Remarks

Are subject to a warm-up period of at least 45 minutes

In a controlled electromagnetic environment¹

With configuration: Low-pass 10Hz²

Specifications subject to change without notice

¹ according to IEC 61326-1:2020

² unless otherwise stated

Mechanical information

Material	Aluminium and ABS
Measurements (W x H x D)	30 x 145 x 135mm
Weight	approx. 500 g
Protection class	IP20



Ordering Information

Article number	495329
Accessories	Terminal B4/120-A106, article number 894387
	Terminal B4/350-A106, article number 894488

Gantner Instruments

Austria | Germany | France | Sweden | India | USA | China | Singapore
 Montafonerstraße 4 · A-6780 Schruns · T +43 55 56 · 77 463-0

office@gantner-instruments.com
 www.gantner-instruments.com